

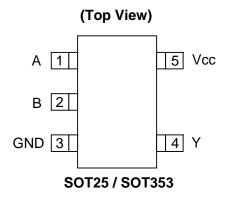
## SINGLE 2 INPUT EXCLUSIVE-OR GATE

### Description

The 74AHCT1G86 is a single 2-input positive exclusive-OR gate with a standard totem pole output. The device is designed for operation with a power supply range of 4.5V to 5.5V. The gate performs the positive Boolean function:

$$Y = A \oplus B$$
 or  $Y = \overline{A}B + A\overline{B}$ 

### Pin Assignments



#### Features

- Supply Voltage Range from 4.5V to 5.5V
- ± 8 mA Output Drive at 5.0V
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time.
- ESD Protection per JESD 22
  - Exceeds 200-V Machine Model (A115-A)
  - Exceeds 2000-V Human Body Model (A114-A)
  - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- SOT25 and SOT353: Assembled with "Green" Molding Compound (no Br, Sb)
- Lead Free Finish / RoHS Compliant (Note 1)

### Applications

- General Purpose Logic
- Wide array of products such as:
  - o PCs, networking, notebooks, netbooks, PDAs
  - o Computer peripherals, hard drives, CD/DVD ROM
  - $\circ$   $\;$  TV, DVD, DVR, set top box
  - o Phones, Personal Navigation / GPS
  - o MP3 players ,Cameras, Video Recorders

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead\_free.html.

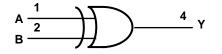


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## **Pin Descriptions**

Pin Name	Pin No	Description
A	1	Data Input
В	2	Data Input
GND	3	Ground
Y	4	Data Output
V <sub>CC</sub>	5	Supply Voltage

# Logic Diagram



## **Function Table**

Inp	Output	
Α	В	Y
Н	Н	L
L	Н	Н
Н	L	Н
L	L	L



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## Absolute Maximum Ratings (Note 2)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V <sub>CC</sub>	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state	-0.5 to V <sub>CC</sub> +0.5	V
I <sub>IK</sub>	Input Clamp Current VI<0	-20	mA
I <sub>OK</sub>	Output Clamp Current ( $V_O < 0$ or $V_O > V_{CC}$ )	±20	mA
lo	Continuous output current ( $V_0 = 0$ to $V_{CC}$ )	±25	mA
I <sub>CC</sub>	Continuous current through V <sub>CC</sub>	50	mA
I <sub>GND</sub>	Continuous current through GND	-50	mA
TJ	T <sub>J</sub> Operating Junction Temperature		°C
T <sub>STG</sub>	Storage Temperature	-65 to 150	°C

Notes: 2. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

## **Recommended Operating Conditions (Note 3)**

Symbol		Parameter	Min	Max	Unit
V <sub>CC</sub>	Operating Voltage		4.5	5.5	V
VIH	High-level Input Voltage		2.0		V
VIL	Low-level input voltage			0.8	V
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	V <sub>CC</sub>	V
I <sub>OH</sub>	High-level output current			-8	mA
I <sub>OL</sub>	Low-level output current			8	mA
Δt/ΔV	Input transition rise or fall rate			20	ns/V
T <sub>A</sub>	Operating free-air temperature		-40	125	°C

Notes: 3. Unused inputs should be held at  $V_{\mbox{CC}}$  or Ground.



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## **Electrical Characteristics**

		T ( 0 )			25⁰C		-40ºC t	o 85⁰C	-40°C to	o 125⁰C	
Symbol	Parameter	Test Conditions	V <sub>CC</sub>	Min	Тур.	Max	Min	Max	Min	Max	Unit
	High Level	Ι <sub>ΟΗ</sub> = -50μΑ	4.5V	4.4	4.5		4.4		4.4		. /
V <sub>OH</sub>	Output Voltage	I <sub>OH</sub> = -8mA	4.5V	3.94			3.8		3.70		V
N/	Low Level	I <sub>OL</sub> = 50μA	4.5V		0	0.1		0.1		0.1	V
V <sub>OL</sub>	Output Voltage	$I_{OL} = 8mA$	4.5V			0.36		0.44		0.55	V
l <sub>l</sub>	Input Current	$V_1 = 5.5V$ or GND	0 to 5.5V			± 0.1		± 1		±2	μA
I <sub>CC</sub>	Supply Current	$V_{I} = 5.5V \text{ or GND}$ $I_{O}=0$	5.5V			1		10		40	μA
Ci	Input Capacitance	V <sub>I</sub> = V <sub>CC</sub> – or GND	5.5V		2.0	10		10		10	pF
ΔI <sub>CC</sub>	Additional Supply Current	One input at 3.4 V Other inputs at V <sub>CC</sub> or GND	5.5V			1.35		1.5			mA
	Thermal Resistance	SOT25			204						0.0.0.4
$\theta_{JA}$	Junction-to- Ambient	SOT353	(Note 4)		371						°C/W
	Thermal Resistance	SOT25			52						°0.00
θ <sub>JC</sub>	Junction-to- Case	SOT353	(Note 4)		143						°C/W

Note: 4. Test conditions for SOT25, and SOT353: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

## **Switching Characteristics**

#### $V_{cc} = 5V \pm 0.5V$ (see Figure 1)

Deremeter	From	то			25⁰C		-40°C to 85°C		-40°C to 125°C		Unit
Parameter	(Input)	(OUTPUT)		Min	Тур.	Max	Min	Max	Min	Max	Unit
	A or D	V	C <sub>L</sub> =15pF	0.6	3.5	6.9	0.6	8.0	0.6	9.0	ns
t <sub>pd</sub>	A or B	ľ	C <sub>L</sub> =50pF	0.6	5.0	7.9	0.6	9.0	0.6	10.5	ns

### **Operating Characteristics**

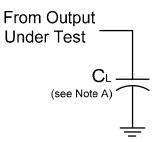
T<sub>A</sub> = 25 °C

	Parameter	Test Conditions	V <sub>CC</sub> = 5V Typ.	Unit
C <sub>pd</sub>	Power dissipation capacitance	f = 1 MHz No Load	15	pF

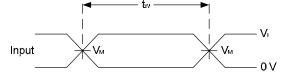


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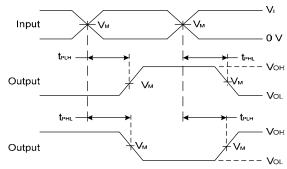
### **Parameter Measurement Information**



М	Inj	outs	V	C
V <sub>CC</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	υL
5V±0.5V	3V	≤3ns	1.5V	15pF
5V±0.5V	3V	≤3ns	1.5V	50pF



**Voltage Waveform Pulse Duration** 



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Notes: A. Includes test lead and test apparatus capacitance.

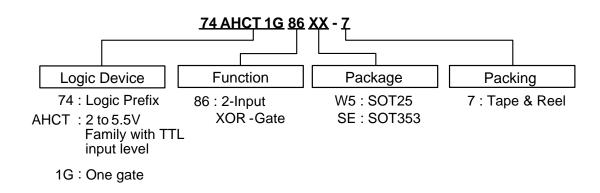
- B. All pulses are supplied at pulse repetition rate  $\leq$  1 MHz.
- C. Inputs are measured separately one transition per measurement.
- D.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd.}$

74AHCT1G86 Document number: DS35185 Rev. 1 - 2



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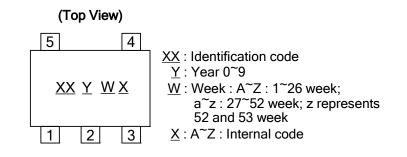
### **Ordering Information**



	Device	Package	Packaging	7" Tape and Reel	
	Device	Code	(Note 5)	Quantity	Part Number Suffix
<b>Pb</b> ,	74AHCT1G86W5-7	W5	SOT25	3000/Tape & Reel	-7
₽9,	74AHCT1G86SE-7	SE	SOT353	3000/Tape & Reel	-7

Notes: 5. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

## **Marking Information**



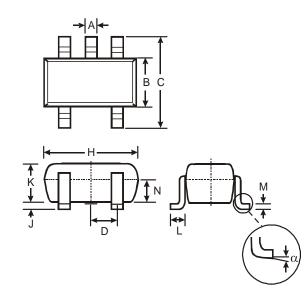
Part Number	Package	Identification Code
74AHCT1G86W5	SOT25	ZX
74AHCT1G86SE	SOT353	ZX



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## Package Outline Dimensions (All Dimensions in mm)

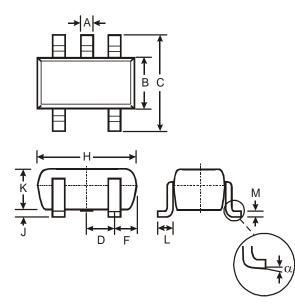
### (1) Package Type: SOT25



	SOT	[25	
Dim	Min	Max	Тур
Α	0.35	0.50	0.38
В	1.50	1.70	1.60
С	2.70	3.00	2.80
D	_		0.95
н	2.90	3.10	3.00
J	0.013	0.10	0.05
κ	1.00	1.30	1.10
L	0.35	0.55	0.40
М	0.10	0.20	0.15
N	0.70	0.80	0.75
α	0°	8°	_
All D	imensi	ons in	mm

#### (2) Package Type: SOT353

NEW PRODUCT



Dim	Min	Max			
Α	0.10	0.30			
В	1.15	1.35			
С	2.00	2.20			
D	0.65 Typ				
F	0.40	0.45			
Н	1.80	2.20			
J	0	0.10			
Κ	0.90	1.00			
L	0.25	0.40			
М	0.10	0.22			
α	0°	8°			
All Di	mensions	in mm			



## SINGLE 2 INPUT EXCLUSIVE-OR GATE

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